

科目	電子學	適用系所	通訊工程學系	時間	100 分鐘
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※請務必在答案卷作答區內作答。 共 3頁第 1頁

1. Assume the diodes are ideal, then find the values of I and V in the circuits shown in Fig. 1 (Describe carefully how to get the solutions for part (e) and part (f).) ((a) 2%, (b) 2%, (c) 2%, (d)2%, (e) 4%, and (f) 4%)

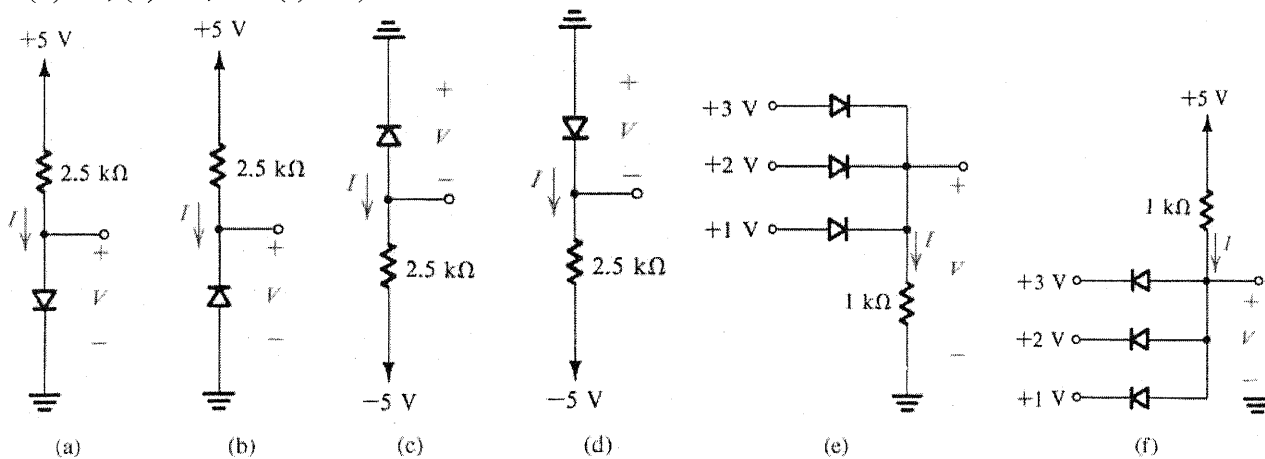


Fig. 1

2. Refer to Fig. 2 and assume ideal op amps,
 (a) Find the voltage gain v_o/v_i , (8%)
 (b) Find the input resistance R_{in} . (8%)
 (Describe carefully how to get all the solutions.)

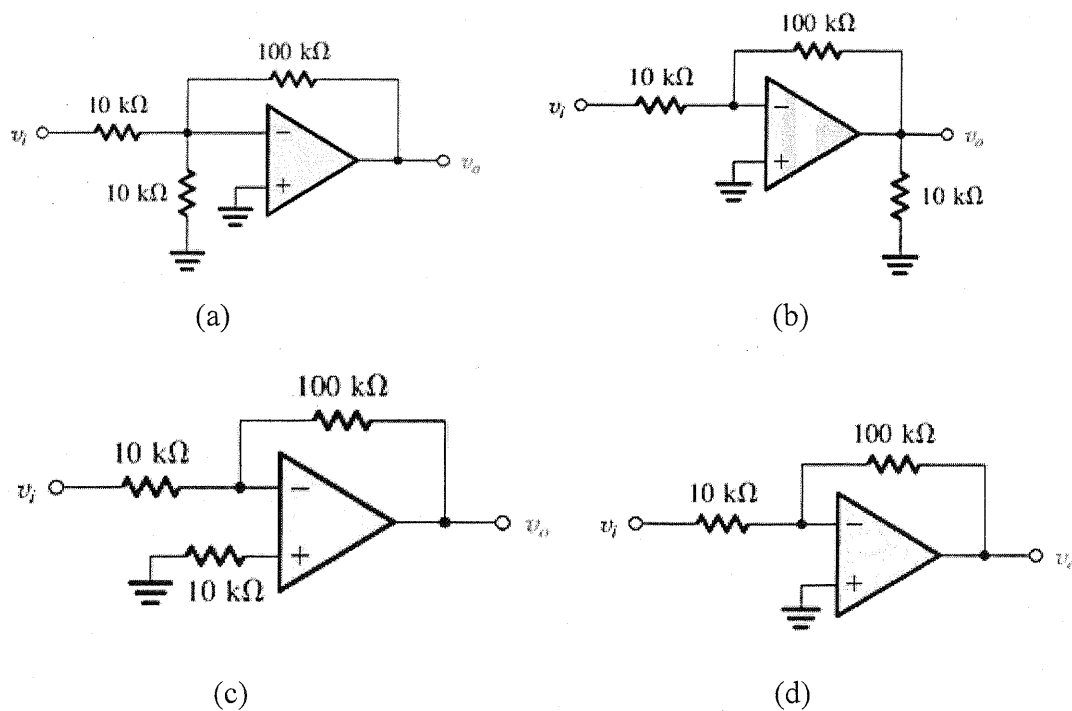


Fig. 2

3. Assuming that the diodes in the circuit of Fig. 3 are ideal, find the values of the labeled voltages and currents. ((a) 6%, (b) 6%, (c) 6%)

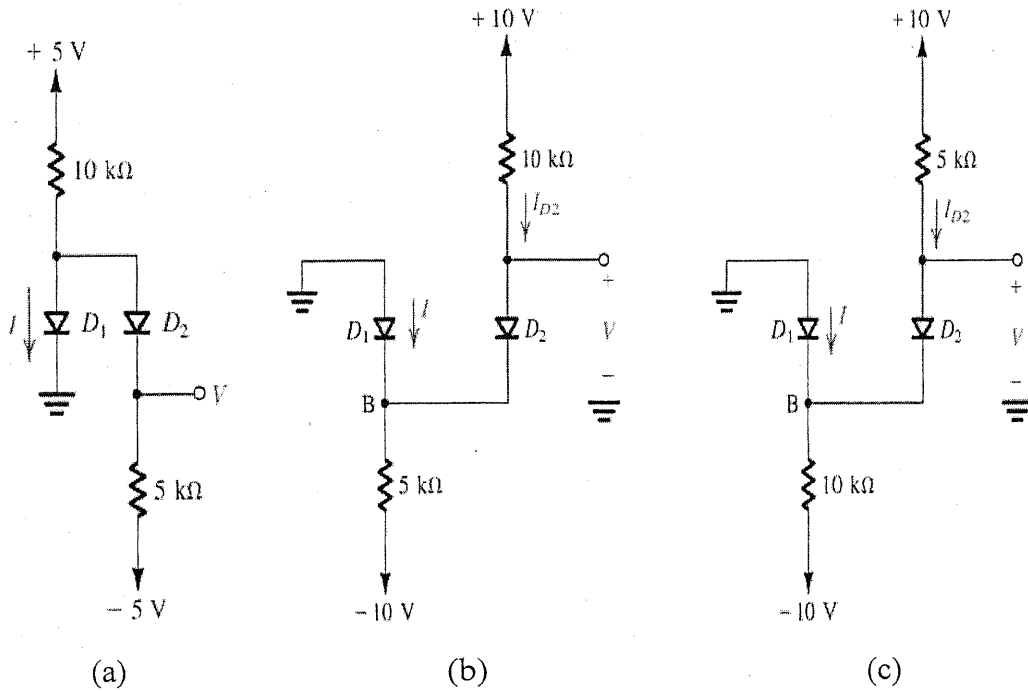


Fig. 3

4. If we use constant-voltage-drop diode model shown in Fig. 4(a) for the diode used in Fig. 4(b),
 (a) plot v_o versus v_i for $-10V \leq v_i \leq 10V$. Indicate all breakpoints. (5%)
 (b) plot i_D over the same range of input voltage. (5%)

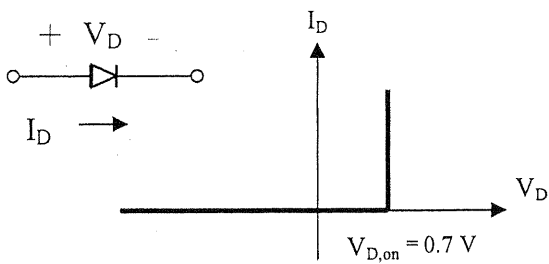


Fig. 4(a)

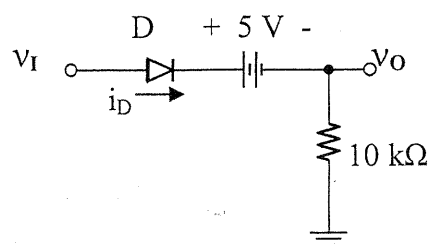


Fig. 4(b)

5. For the circuit shown in Fig. 5, if $\lambda = 0$, $K_n = 60 \text{ mA/V}^2$, $V_{TN} = 0.4 \text{ V}$.

(a) Determine the quiescent values V_{GSQ} and V_{DSQ} . (8%)

(b) Find the small-signal parameters g_m and r_o . (8%)

(c) Find R_{in} , R_{out} , and v_{out} / v_{in} . (8%)

** For NMOS in saturation region, $i_D = K_n (v_{GS} - V_{TN})^2 (1 + \lambda v_{DS})$

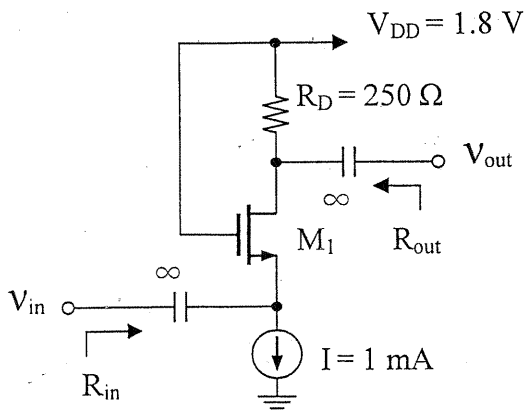


Fig. 5

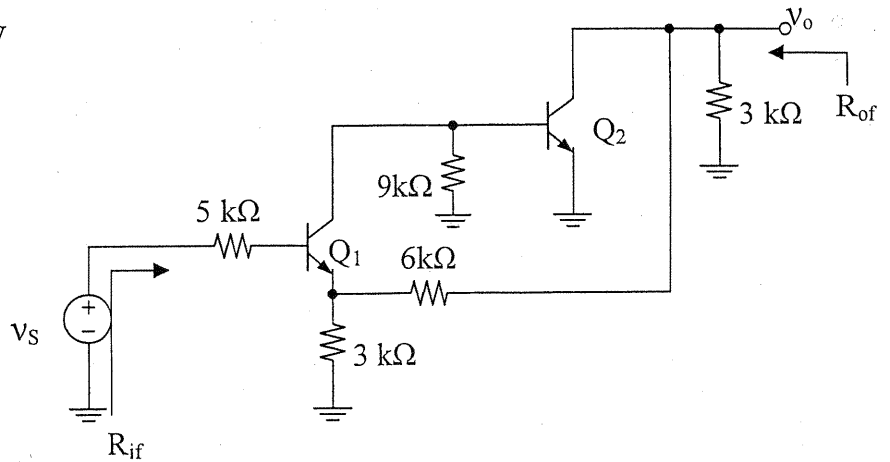


Fig. 6

6. The circuit shown in Fig. 6 is an AC circuit for a feedback amplifier, transistors Q1 and Q2 have the following parameters: $r_{\pi 1} = 5 \text{ k}\Omega$, $r_{\pi 2} = 2.5 \text{ k}\Omega$, and $\beta_{o1} = \beta_{o2} = 100$.

(a) Find the input resistance R_{if} and the output resistance R_{of} . (8%)

(b) Find the voltage gain $\frac{v_o}{v_s}$. (8%)